## NSN 5962-01-234-1361

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View Online at https://aerobasegroup.com/nsn/5962-01-234-1361 **Body Length:** 0.380 inches **Body Width:** Between 0.340 inches and 0.380 inches **Body Height:** 0.085 inches **Maximum Power Dissipation Rating:** 794.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Om-51a/fr **Features Provided:** Hermetically sealed and burn in and programmable and schottky and 3-state output and w/enable **Inclosure Material:** Ceramic **Inclosure Configuration:** Flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 12 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 7.0 volts power source **Time Rating Per Chacteristic:** 85.00 nanoseconds propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Prom **Precious Material And Location:** Terminal surface option gold **Precious Material:** Gold

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Shelf Life:

N/a

24 flat leads

**Test Data Document:** 

**Terminal Type And Quantity:** 

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**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

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